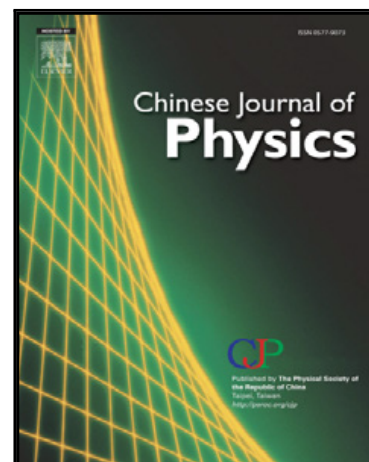


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A Short Review on: Optimization Techniques of ZnO based Thin Film Transistors

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Highlights

- Introduction to TFT
- Important application of ZnO thin film transistor has been discussed.
- Various techniques that can be used to improve the quality of ZnO based thin film transistor have been reviewed.
- Work from reputed research group has been summarized.

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